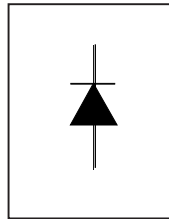


International  
**IR** Rectifier

**QUIETIR** Series  
 8EWF12S

**SURFACE MOUNTABLE FAST  
 SOFT RECOVERY DIODE**  
 Lead-Free ("PbF" suffix)



$$V_F < 1.3V @ 8A$$

$$t_{rr} = 80ns$$

$$V_{RRM} = 1200V$$

#### Description/ Features

The 8EWF12SPbF fast soft recovery **QUIETIR** rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

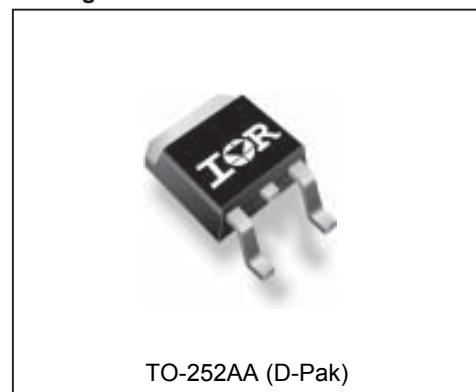
Typical applications are both:

- Output rectification and freewheeling diode in inverters, choppers and converters.
- Input rectifications where severe restrictions on conducted EMI should be met.

#### Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Sinusoidal waveform	8	A
$V_{RRM}$	1200	V
$I_{FSM}$	170	A
$V_F$ @8A, $T_J=25^\circ C$	1.3	V
$t_{rr}$ @1A, 100A/ $\mu s$	80	ns
$T_J$ range	-40 to 150	$^\circ C$

#### Package Outline



Voltage Ratings

Part Number	$V_{RRM}$ , maximum peak reverse voltage V	$V_{RSM}$ , maximum non repetitive peak reverse voltage V	$I_{RRM}$ 150°C mA
8EWF12SPbF	1200	1300	4

Absolute Maximum Ratings

Parameters	8EWF	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	8	A	@ $T_C = 94^\circ\text{C}$ , 180° conduction half sine wave
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current	170	A	10ms Sine pulse, rated $V_{RRM}$ applied
	200		10ms Sine pulse, no voltage reapplied
$I^2t$ Max. $I^2t$ for fusing	144	$A^2s$	10ms Sine pulse, rated $V_{RRM}$ applied
	200		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	2000	$A^2/s$	$t = 0.1$ to 10ms, no voltage reapplied

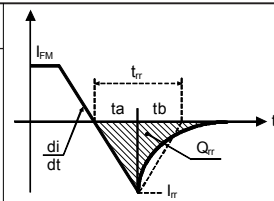
Electrical Specifications

Parameters	8EWF	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop	1.3	V	@ 8A, $T_J = 25^\circ\text{C}$
$r_t$ Forward slope resistance	25.6	$m\Omega$	$T_J = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.93	V	
$I_{RM}$ Max. Reverse Leakage Current	0.1	mA	$T_J = 25^\circ\text{C}$
	4		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

Typical Reverse Recovery Characteristics

Parameters	8EWF	Units	Conditions
$t_{rr}$ Reverse Recovery Time	270	ns	$I_F @ 8\text{Apk}$ @ 25A/ $\mu\text{s}$ @ $T_J = 25^\circ\text{C}$
$I_{rr}$ Reverse Recovery Current	4.2	A	
$Q_{rr}$ Reverse Recovery Charge	1	$\mu\text{C}$	
S Typical Snap Factor $t_b/t_a$	0.6	-	



Thermal-Mechanical Specifications

Parameters	8EWF	Units	Conditions
$T_J$ Max. Junction Temperature Range	-40 to 150	°C	
$T_{stg}$ Max. Storage Temperature Range	-40 to 150	°C	
	Soldering Temperature	240	°C for 10 seconds
$R_{thJC}$ Max. Thermal Resistance Junction to Case	2.5	°C/W	DC operation
$R_{thJA}$ Typ. Thermal Resistance Junction to Ambient (PCB Mount)**	50	°C/W	
wt Approximate Weight	1(0.03)	g(oz.)	
T Case Style	TO-252AA (D-Pak)		
Marking Device	8EWF12S		

\*\* When mounted on 1" square (650mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz (140µm) copper 40°C/W  
For recommended footprint and soldering techniques refer to application note #AN-994

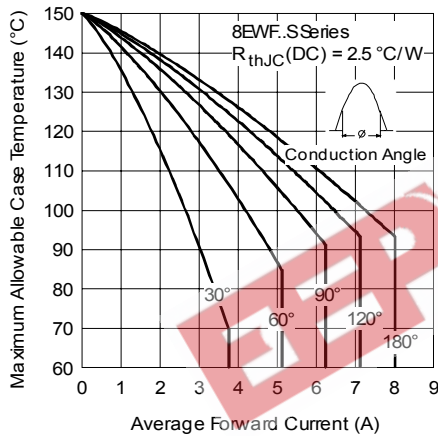


Fig. 1 - Current Rating Characteristics

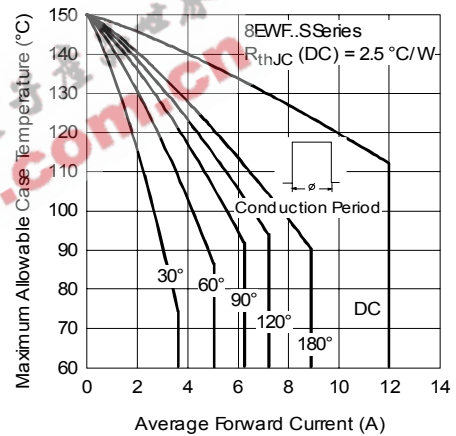


Fig. 2 - Current Rating Characteristics

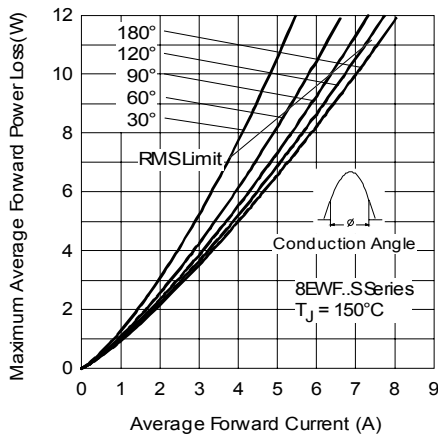


Fig. 3 - Forward Power Loss Characteristics

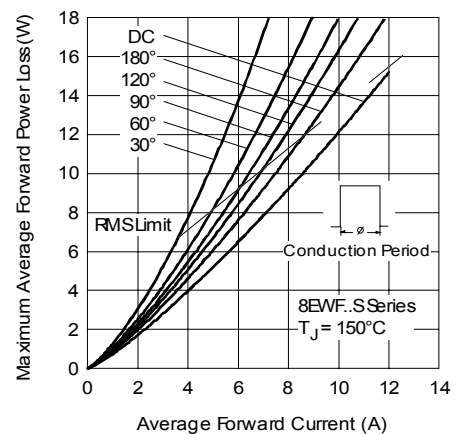


Fig. 4 - Forward Power Loss Characteristics

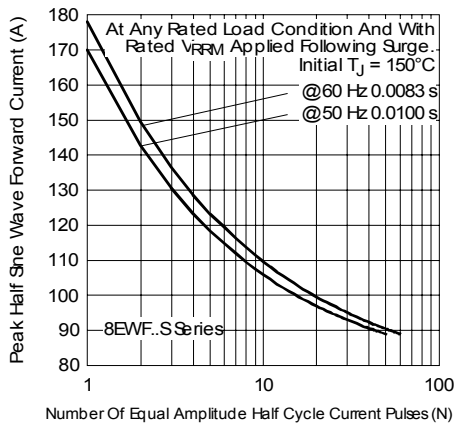


Fig. 5 - Maximum Non-Repetitive Surge Current

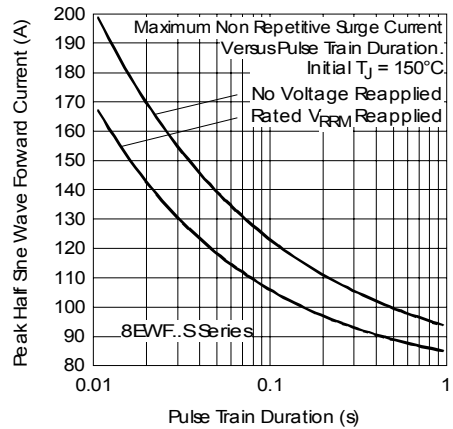


Fig. 6 - Maximum Non-Repetitive Surge Current

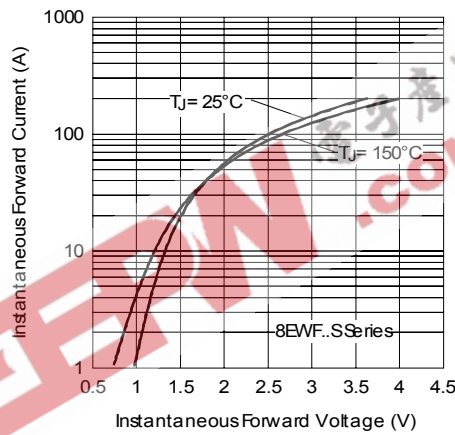


Fig. 7 - Forward Voltage Drop Characteristics

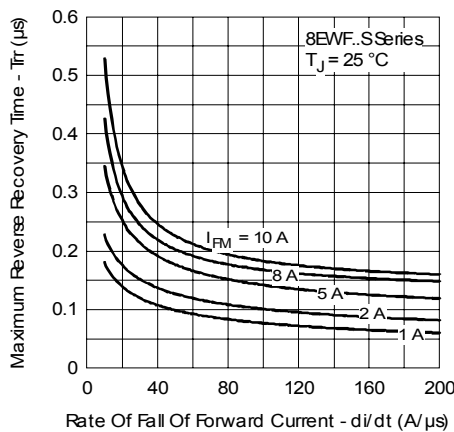


Fig. 8 - Recovery Time Characteristics,  $T_J = 25^\circ\text{C}$

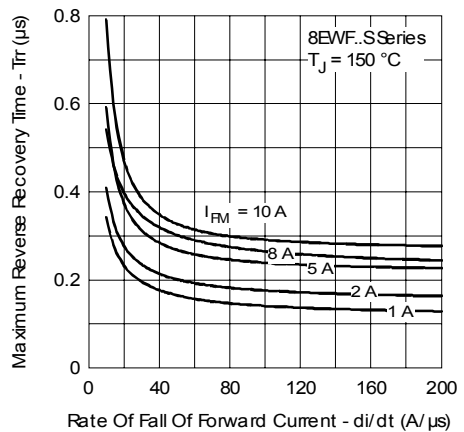


Fig. 9 - Recovery Time Characteristics,  $T_J = 150^\circ\text{C}$

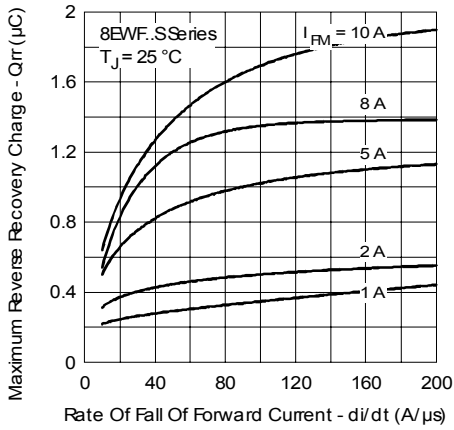


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25^\circ\text{C}$

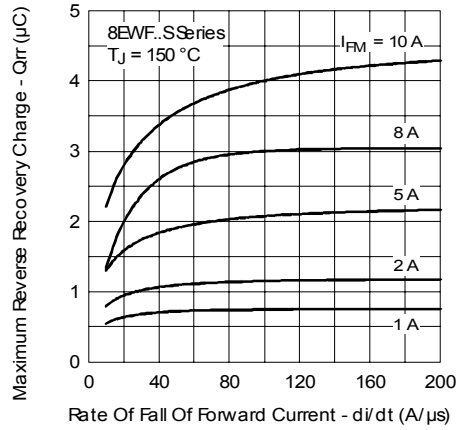


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150^\circ\text{C}$

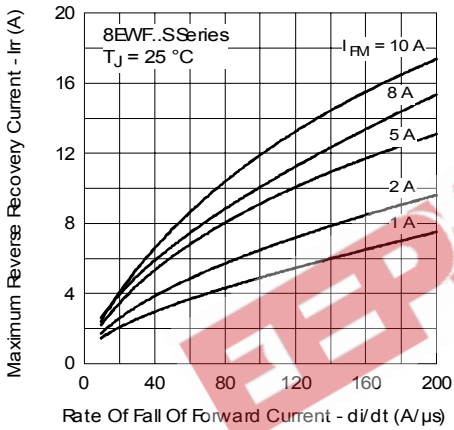


Fig. 12 - Recovery Current Characteristics,  $T_J = 25^\circ\text{C}$

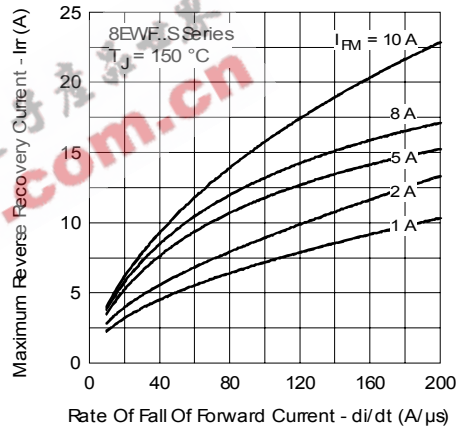


Fig. 13 - Recovery Current Characteristics,  $T_J = 150^\circ\text{C}$

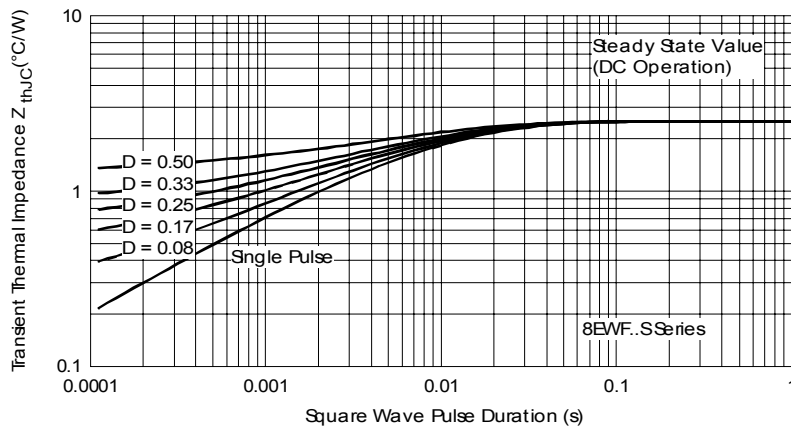
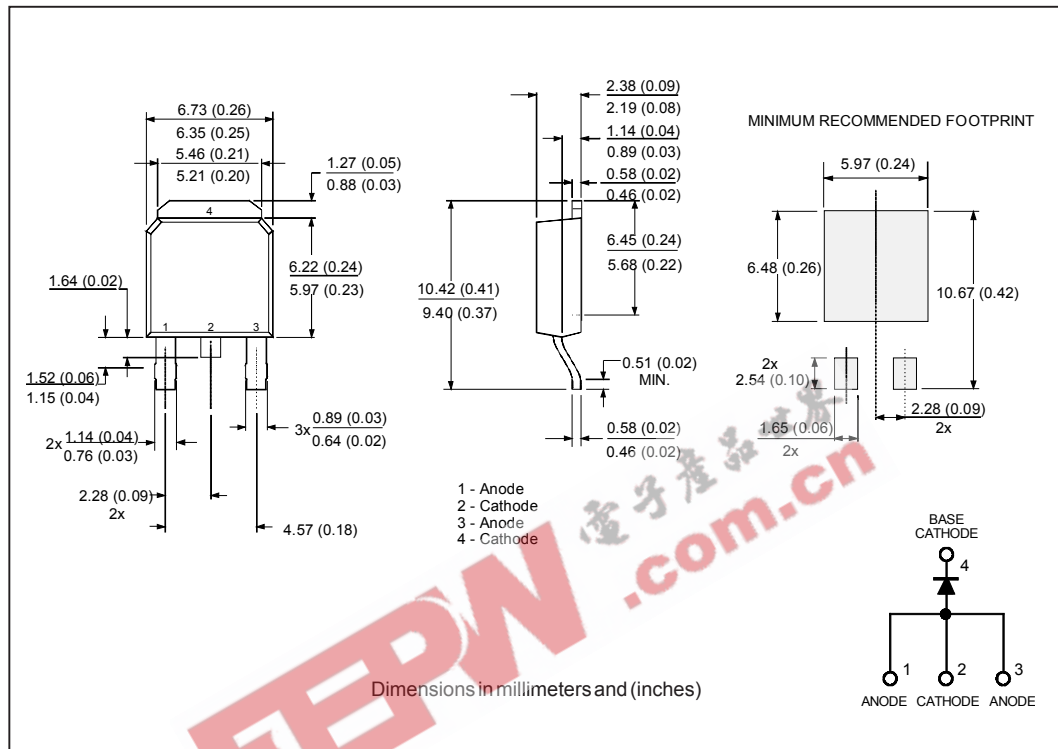
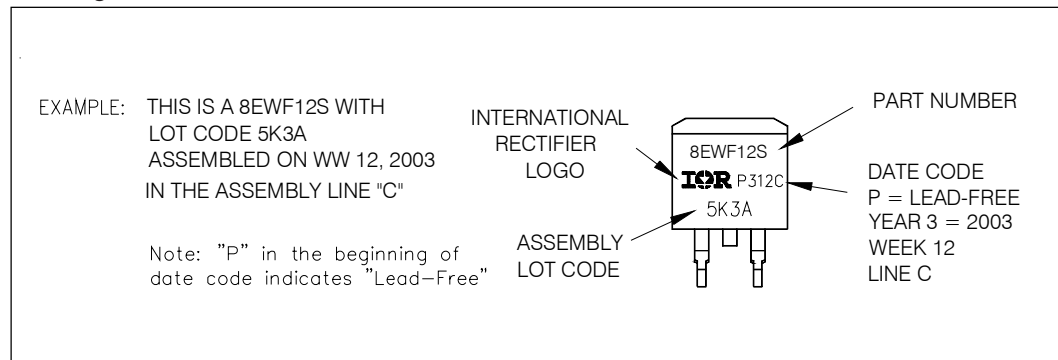


Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics

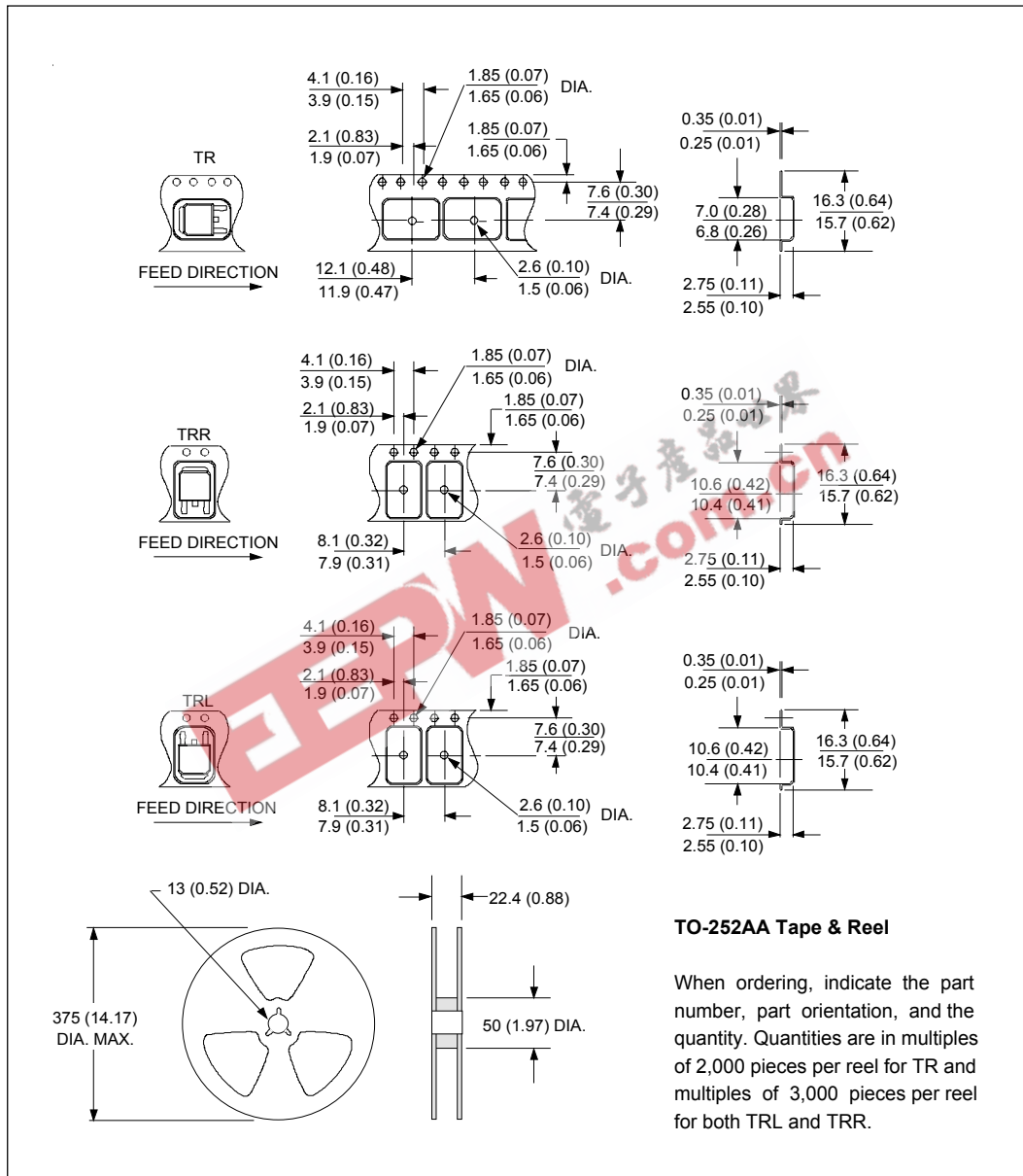
Outline Table



Marking Information



Tape & Reel Information



Ordering Information Table

Device Code							
8	E	W	F	12	S	TR	PbF
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
<b>1</b>	-	Current Rating (8 = 8A)					
<b>2</b>	-	Circuit Configuration: E = Single Diode					
<b>3</b>	-	Package: W = D-Pak					
<b>4</b>	-	Type of Silicon: F = Fast Soft Recovery Rectifier					
<b>5</b>	-	Voltage Rating (12 = 1200V)					
<b>6</b>	-	S = Surface Mountable					
<b>7</b>	-	<ul style="list-style-type: none"> <li>• TR = Tape &amp; Reel</li> <li>• TRR = Tape &amp; Reel (Right Oriented)</li> <li>• TRL = Tape &amp; Reel (Left Oriented)</li> </ul>					
<b>8</b>	-	<ul style="list-style-type: none"> <li>• none = Standard Production</li> <li>• PbF = Lead-Free</li> </ul>					

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level and Lead-Free.  
Qualification Standards can be found on IR's Web site.

International  
**IR** Rectifier

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